

## AD8665/AD8666/AD8668

### FEATURES

**Offset voltage: 2.5 mV max**  
**Low input bias current: 1 pA max**  
**Single-supply operation: 5 V to 16 V**  
**Dual-supply operation:  $\pm 2.5$  V to  $\pm 8$  V**  
**Low noise: 8 nV/ $\sqrt{\text{Hz}}$  @ 10 kHz**  
**Wide bandwidth: 4 MHz**  
**Rail-to-rail output**  
**Unity-gain stable**  
**Lead-free packaging**

### APPLICATIONS

**Sensor amplification**  
**Reference buffers**  
**Medical equipment**  
**Physiological measurements**  
**Signal filters and conditioning**  
**Consumer audio**  
**Photodiode amplification**  
**ADC driver**  
**Level shifting circuits**

### GENERAL DESCRIPTION

The AD866x family are single supply, rail-to-rail output amplifiers with low noise performance featuring an extended operating range with supply voltages up to 16 V. They also feature low input bias currents, wide signal bandwidth, and low input voltage and current noise. For lower offset voltage, choose the AD8661/AD8662/AD8664 family.

The combination of low offsets, very low input bias currents, and wide supply range make these amplifiers useful in a wide variety of cost sensitive applications normally associated with much higher priced JFET amplifiers. Systems using high impedance sensors, such as photo diodes, benefit from the combination of low input bias current, low noise, and low offset and bandwidth. The wide operating voltage range matches high performance ADCs and DACs. Audio applications and medical monitoring equipment can take advantage of the high input impedance, low voltage and current noise, wide bandwidth, and the lack of popcorn noise found in many other low input bias current amplifiers.

The AD866x family is specified over the extended industrial temperature range ( $-40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ ).

### PIN CONFIGURATIONS

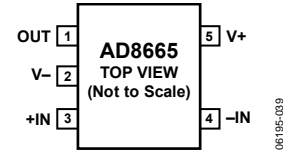


Figure 1. AD8665, 5-Lead SOT-23 (RJ-5)

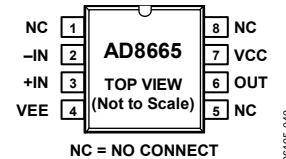


Figure 2. AD8665, 8-Lead SOIC\_N (R-8)

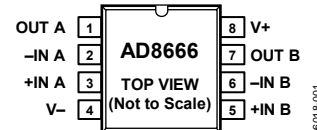


Figure 3. AD8666, 8-Lead SOIC\_N (R-8)

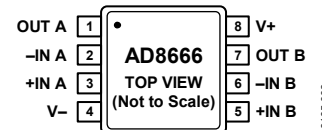


Figure 4. AD8666, 8-Lead MSOP (RM-8)

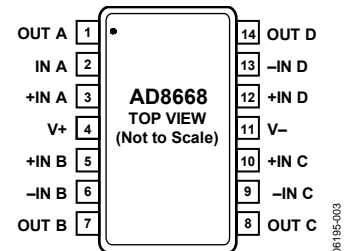


Figure 5. AD8668, 14-Lead TSSOP (RU-14)

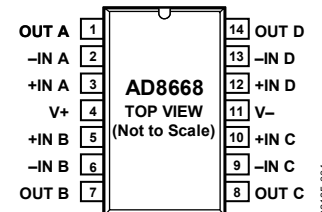


Figure 6. AD8668, 14-Lead SOIC\_N (R-14)

#### Rev. A

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## **REVISION HISTORY**

### **10/06—Rev. 0 to Rev. A**

Added AD8665 .....	Universal
Added New Figure 1 and Figure 2, Renumbered Sequentially.....	1
Changes to Table 4.....	5
Changes to Figure 8, Figure 9, and Figure 11 .....	6
Change to Figure 40 .....	11
Updated Outline Dimensions .....	12
Changes to Ordering Guide .....	13

### **4/06—Rev 0: Initial Version**

## SPECIFICATIONS

$V_{DD} = 5.0\text{ V}$ ,  $V_{CM} = V_{DD}/2$ ,  $T_A = 25^\circ\text{C}$ , unless otherwise noted.

Table 1.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
INPUT CHARACTERISTICS						
Offset Voltage	$V_{OS}$	$V_{CM} = 2.5\text{ V}$ $V_{CM} = -0.1\text{ V to }+3.0\text{ V}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$		0.7	2.5	mV
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$	$-40^\circ\text{C} < T_A < +125^\circ\text{C}$		3.0	10	$\mu\text{V}/^\circ\text{C}$
Input Bias Current	$I_B$	$-40^\circ\text{C} < T_A < +125^\circ\text{C}$		0.2	1	pA
Input Offset Current	$I_{OS}$	$-40^\circ\text{C} < T_A < +125^\circ\text{C}$		0.1	0.5	pA
Input Voltage Range	$V_{CM}$		-0.1		+3.0	V
Common-Mode Rejection Ratio	CMRR	$V_{CM} = -0.1\text{ V to }+3.0\text{ V}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$	84	100		dB
Large-Signal Voltage Gain	$A_{VO}$	$R_L = 2\text{ k}\Omega$ , $V_O = 0.5\text{ V to }4.5\text{ V}$	68	145		V/mV
OUTPUT CHARACTERISTICS						
Output Voltage High	$V_{OH}$	$I_{OUT} = 1\text{ mA}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$	4.88	4.93		V
Output Voltage Low	$V_{OL}$	$I_{OUT} = 1\text{ mA}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$	4.86	50	85	V
Short-Circuit Output Current	$I_{SC}$			$\pm 19$	105	mV
Closed-Loop Output Impedance	$Z_{OUT}$	At 1 MHz, $A_V = 1$		50		$\Omega$
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	$V_{DD} = 5.0\text{ V to }16\text{ V}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$	98	115		dB
Supply Current per Amplifier	$I_{SY}$	$-40^\circ\text{C} < T_A < +125^\circ\text{C}$	94	1.1	1.4	dB
					2.0	mA
DYNAMIC PERFORMANCE						
Slew Rate	SR	$R_L = 2\text{ k}\Omega$		3.5		V/ $\mu\text{s}$
Gain Bandwidth Product	GBP			4		MHz
Phase Margin	$\Phi_M$			70		Degrees
NOISE PERFORMANCE						
Peak-to-Peak Noise	$e_n$ p-p	0.1 Hz to 10 Hz		2.4		$\mu\text{V p-p}$
Voltage Noise Density	$e_n$	$f = 1\text{ kHz}$ $f = 10\text{ kHz}$		10		nV/ $\sqrt{\text{Hz}}$
Channel Separation	CS	$f = 10\text{ kHz}$		8		nV/ $\sqrt{\text{Hz}}$
				-115		dB

# AD8665/AD8666/AD8668

$V_{DD} = 16\text{ V}$ ,  $V_{CM} = V_{DD}/2$ ,  $T_A = 25^\circ\text{C}$ , unless otherwise noted.

**Table 2.**

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
<b>INPUT CHARACTERISTICS</b>						
Offset Voltage	$V_{OS}$	$V_{CM} = 8\text{ V}$ $V_{CM} = -0.1\text{ V to }+14.0\text{ V}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$		0.6	2.5	mV
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$	$-40^\circ\text{C} < T_A < +125^\circ\text{C}$		3.0	10	$\mu\text{V}/^\circ\text{C}$
Input Bias Current	$I_B$	$-40^\circ\text{C} < T_A < +125^\circ\text{C}$		0.2	1	pA
Input Offset Current	$I_{OS}$	$-40^\circ\text{C} < T_A < +125^\circ\text{C}$		0.1	0.5	pA
Input Voltage Range	$V_{CM}$	$-40^\circ\text{C} < T_A < +125^\circ\text{C}$	-0.1		+14.0	V
Common-Mode Rejection Ratio	CMRR	$V_{CM} = -0.1\text{ V to }+14.0\text{ V}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$	90	110		dB
Large-Signal Voltage Gain	$A_{VO}$	$R_L = 2\text{ k}\Omega$ , $V_O = 0.5\text{ V to }15.5\text{ V}$	80	255		dB
<b>OUTPUT CHARACTERISTICS</b>						
Output Voltage High	$V_{OH}$	$I_{OUT} = 1\text{ mA}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$	15.94 15.90	15.96		V V
Output Voltage Low	$V_{OL}$	$I_{OUT} = 1\text{ mA}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$		22	40	mV mV
Short-Circuit Output Current	$I_{SC}$			$\pm 140$		mA
Closed-Loop Output Impedance	$Z_{OUT}$	At 1 MHz, $A_V = 1$		50		$\Omega$
<b>POWER SUPPLY</b>						
Power Supply Rejection Ratio	PSRR	$V_{DD} = 5.0\text{ V to }16\text{ V}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$	98 94	115		dB dB
Supply Current per Amplifier	$I_{SY}$	$-40^\circ\text{C} < T_A < +125^\circ\text{C}$		1.15	1.55 2.0	mA mA
<b>DYNAMIC PERFORMANCE</b>						
Slew Rate	SR	$R_L = 2\text{ k}\Omega$		3.5		$\text{V}/\mu\text{s}$
Gain Bandwidth Product	GBP			4		MHz
Phase Margin	$\Phi_M$			73		Degrees
<b>NOISE PERFORMANCE</b>						
Peak-to-Peak Noise	$e_n\text{ p-p}$	0.1 Hz to 10 Hz		2.5		$\mu\text{V p-p}$
Voltage Noise Density	$e_n$	$f = 1\text{ kHz}$ $f = 10\text{ kHz}$		10 8		$\text{nV}/\sqrt{\text{Hz}}$ $\text{nV}/\sqrt{\text{Hz}}$
Channel Separation	CS	$f = 10\text{ kHz}$		-115		dB

## ABSOLUTE MAXIMUM RATINGS

Table 3.

Parameter	Rating
Supply Voltage	18 V
Input Voltage	GND to $V_{DD}$
Differential Input Voltage	$\pm 18$ V
Output Short-Circuit to GND	Indefinite
Storage Temperature Range	$-65^{\circ}\text{C}$ to $+150^{\circ}\text{C}$
Operating Temperature Range	$-40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$
Lead Temperature (Soldering, 60 sec)	$300^{\circ}\text{C}$
Junction Temperature	$150^{\circ}\text{C}$

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## THERMAL RESISTANCE

Table 4. Thermal Resistance

Package Type	$\theta_{JA}$	$\theta_{JC}$	Unit
5-Lead SOT-23 (RJ-5)	240	92	$^{\circ}\text{C}/\text{W}$
8-Lead SOIC_N (R-8)	158	43	$^{\circ}\text{C}/\text{W}$
8-Lead MSOP (RM-8)	210	45	$^{\circ}\text{C}/\text{W}$
14-Lead SOIC (R-14)	120	36	$^{\circ}\text{C}/\text{W}$
14-Lead TSSOP (RU-14)	180	35	$^{\circ}\text{C}/\text{W}$

## ESD CAUTION



**ESD (electrostatic discharge) sensitive device.** Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

## TYPICAL PERFORMANCE CHARACTERISTICS

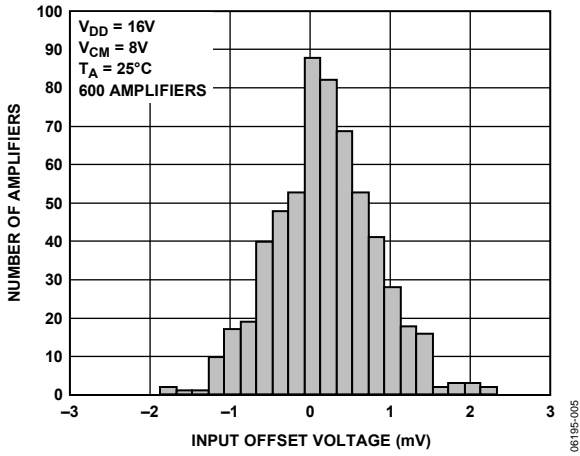


Figure 7. Input Offset Voltage Distribution

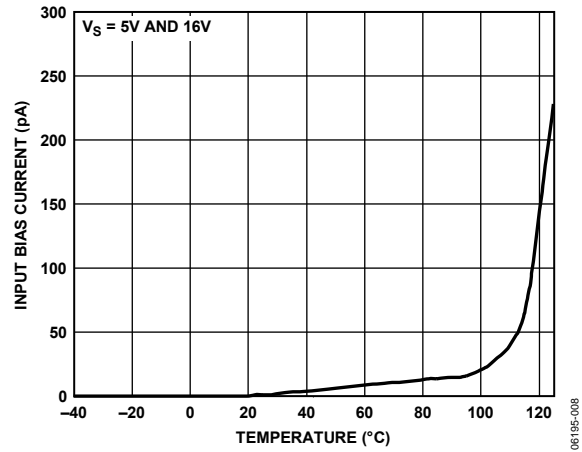


Figure 10. Input Bias Current vs. Temperature

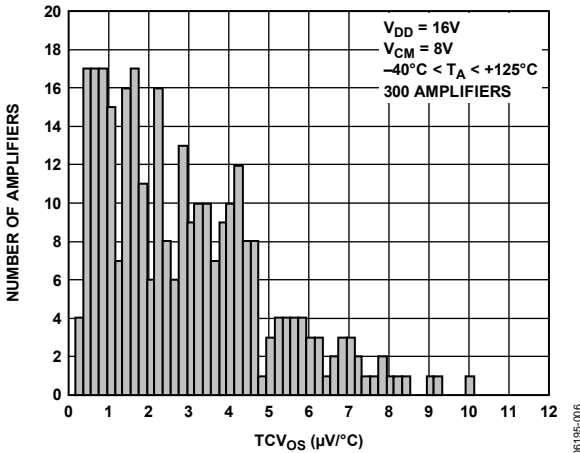


Figure 8.  $V_{OS}$  Drift ( $TCV_{OS}$ ) Distribution

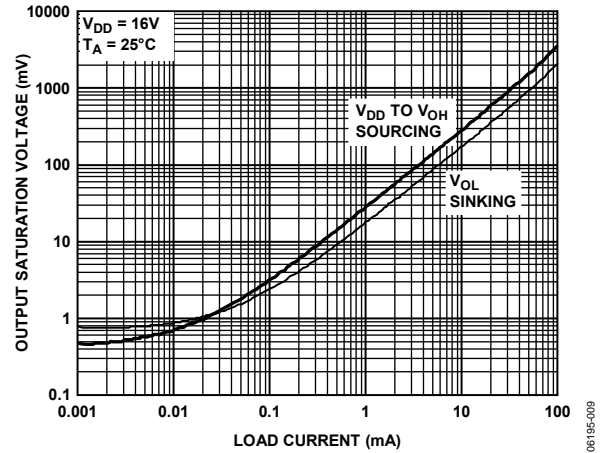


Figure 11. Output Saturation Voltage vs. Load Current

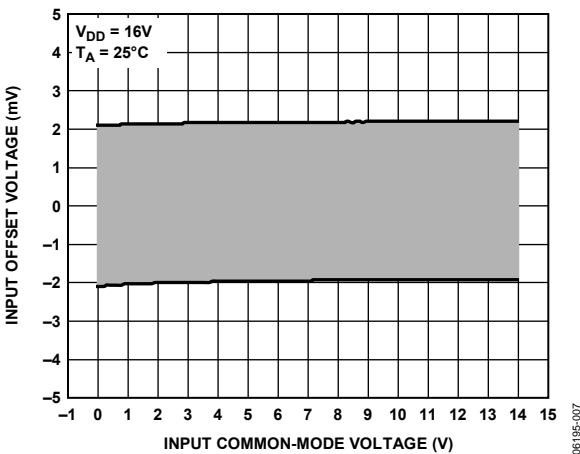


Figure 9. Offset Voltage vs. Common-Mode Voltage

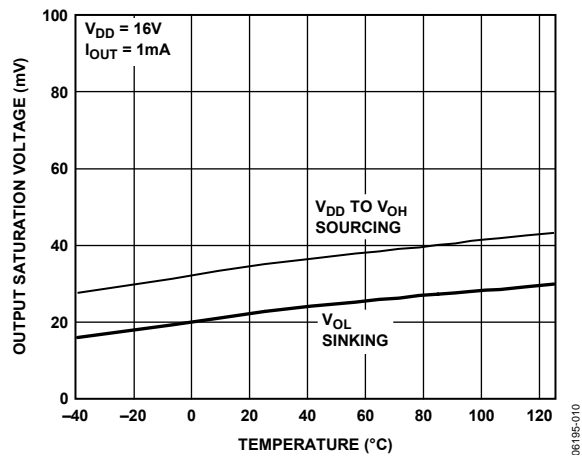


Figure 12. Output Saturation Voltage vs. Temperature

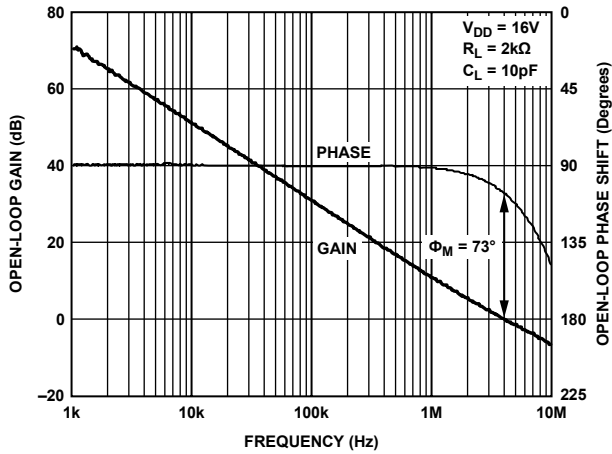


Figure 13. Open-Loop Gain and Phase vs. Frequency

06195-011

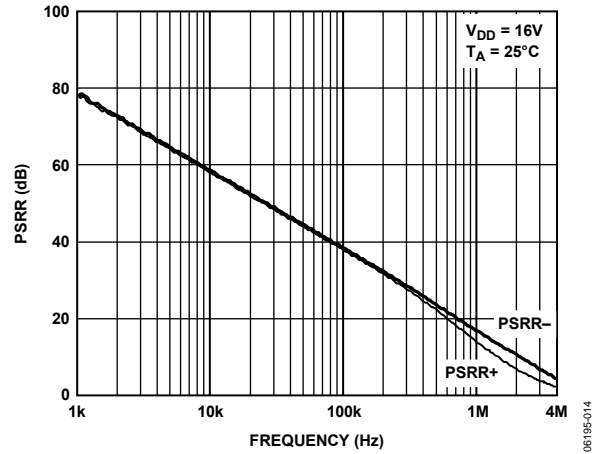


Figure 16. Power Supply Rejection Ratio vs. Frequency

06195-014

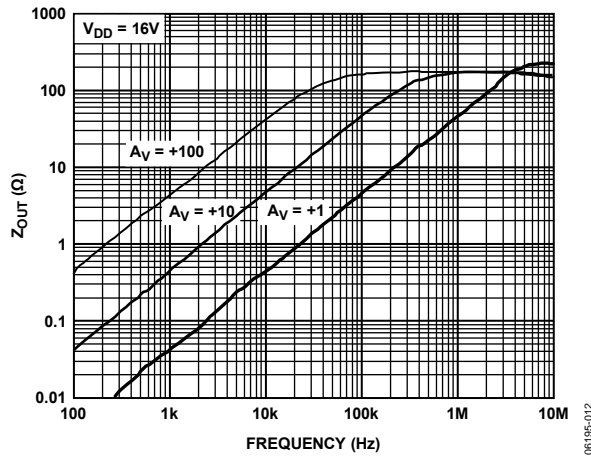


Figure 14. Closed-Loop Output Impedance vs. Frequency

06195-012

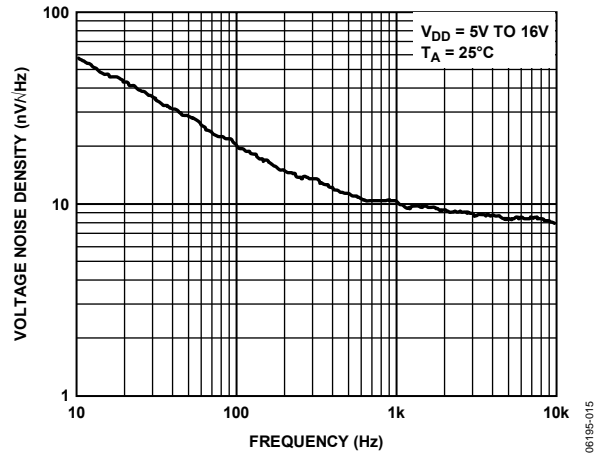


Figure 17. Voltage Noise Density vs. Frequency

06195-015

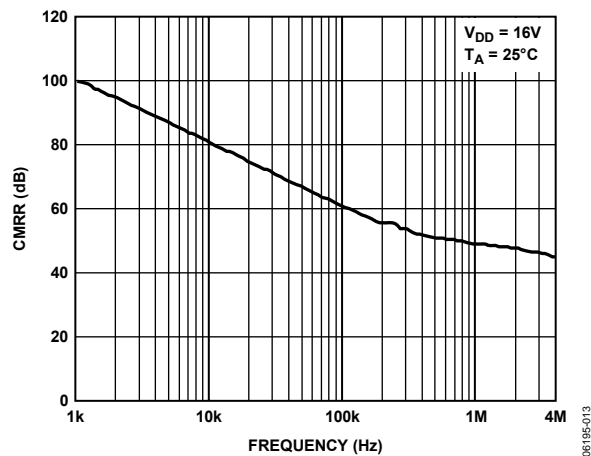


Figure 15. Common-Mode Rejection Ratio vs. Frequency

06195-013

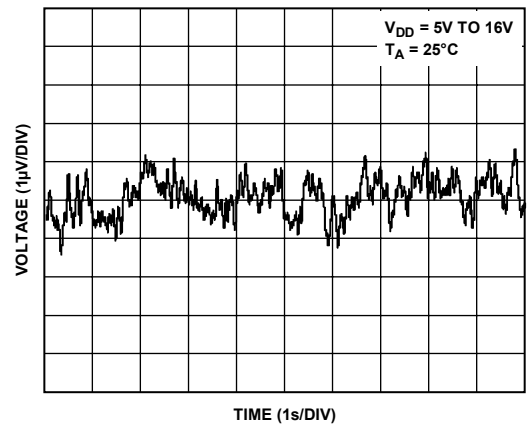


Figure 18. 0.1 Hz to 10 Hz Voltage Noise

06195-016

# AD8665/AD8666/AD8668

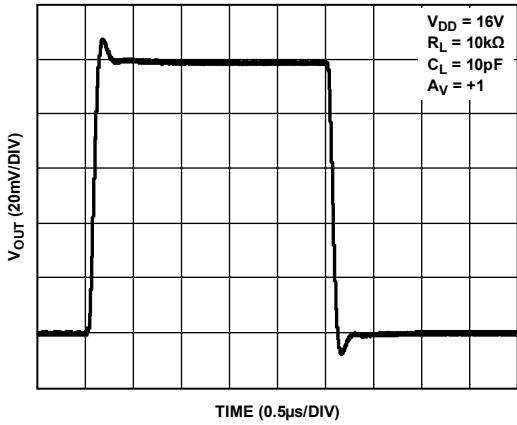


Figure 19. Small-Signal Transient Response

06195-017

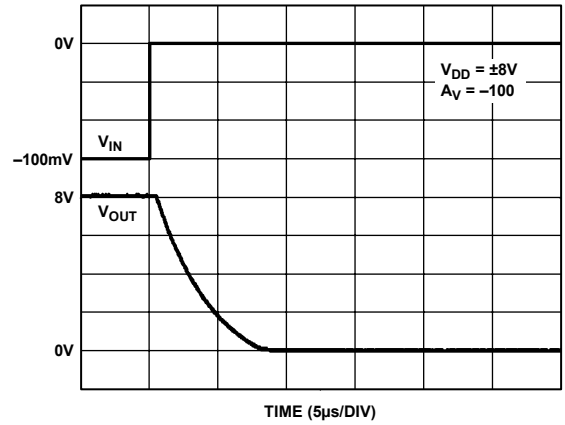


Figure 22. Positive Overload Recovery Time

06195-020

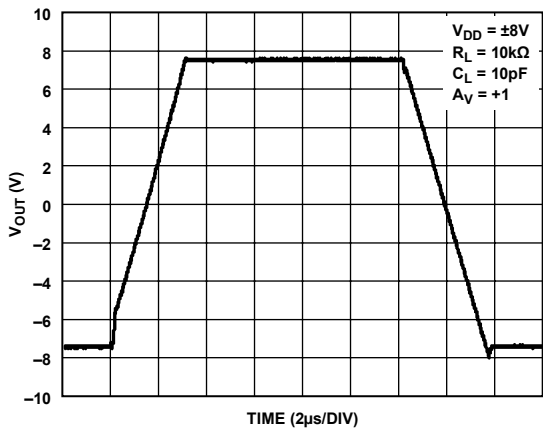


Figure 20. Large-Signal Transient Response

06195-018

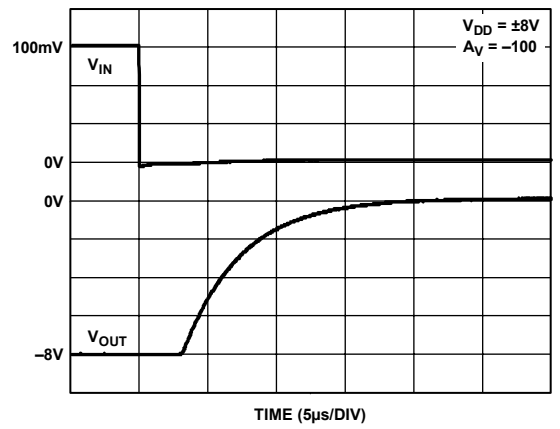


Figure 23. Negative Overload Recovery Time

06195-021

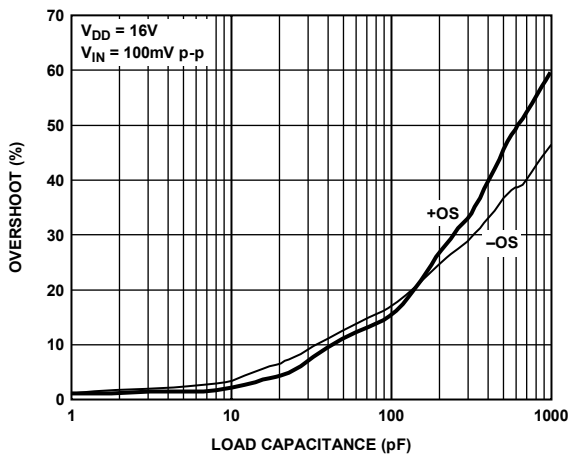


Figure 21. Small-Signal Overshoot vs. Load Capacitance

06195-019

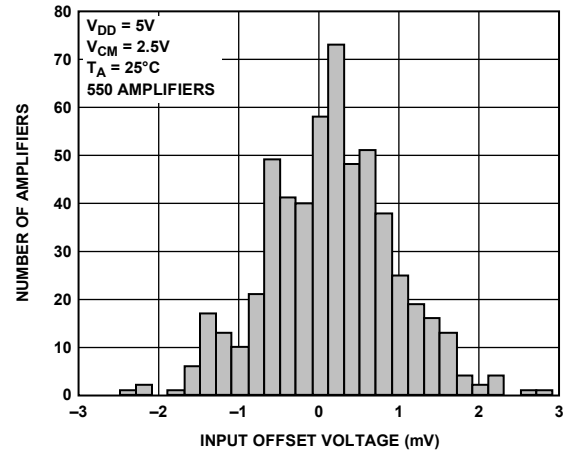


Figure 24. Input Offset Voltage Distribution

06195-022



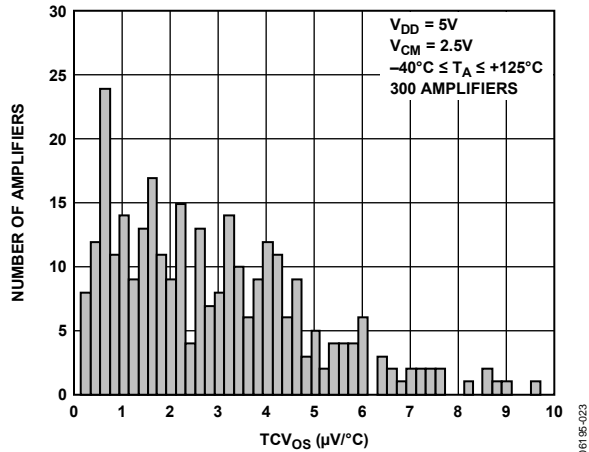


Figure 25.  $V_{OS}$  Drift ( $TCV_{OS}$ ) Distribution

06195-023

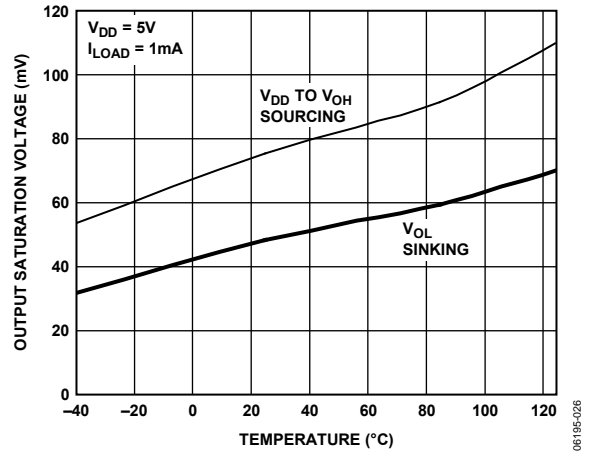


Figure 28. Output Saturation Voltage vs. Temperature

06195-026

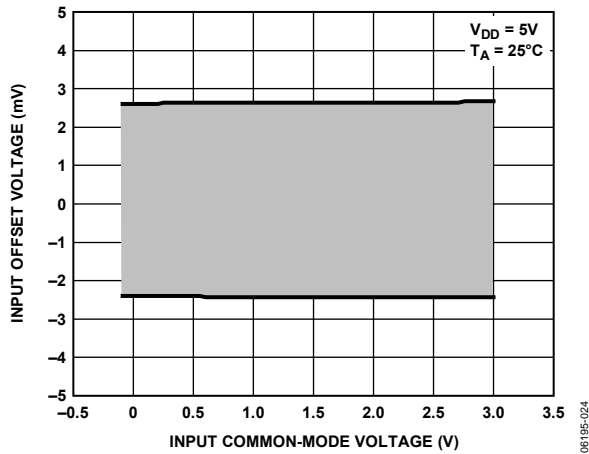


Figure 26. Offset Voltage vs. Common-Mode Voltage

06195-024

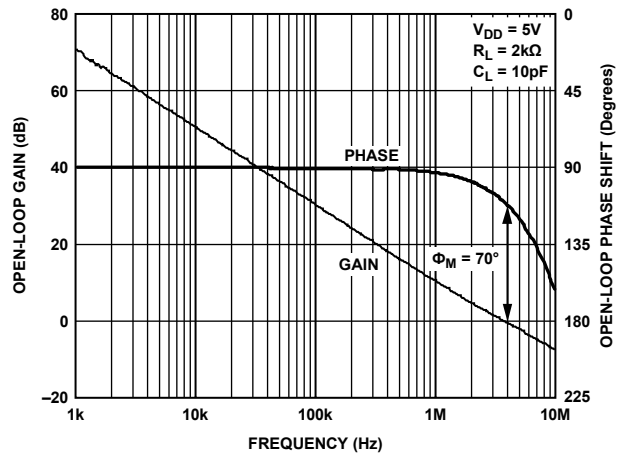


Figure 29. Open-Loop Gain and Phase vs. Frequency

06195-027

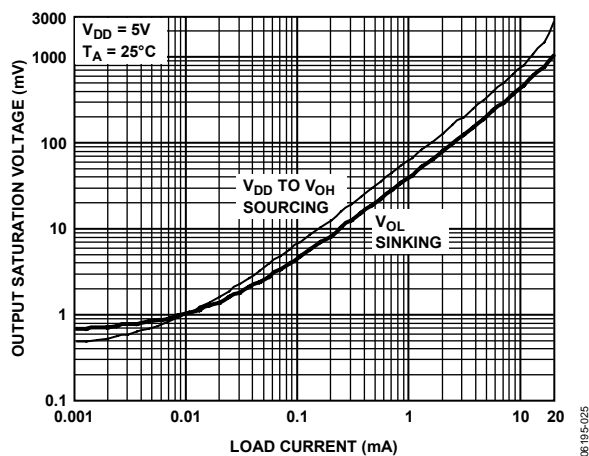


Figure 27. Output Saturation Voltage vs. Load Current

06195-025

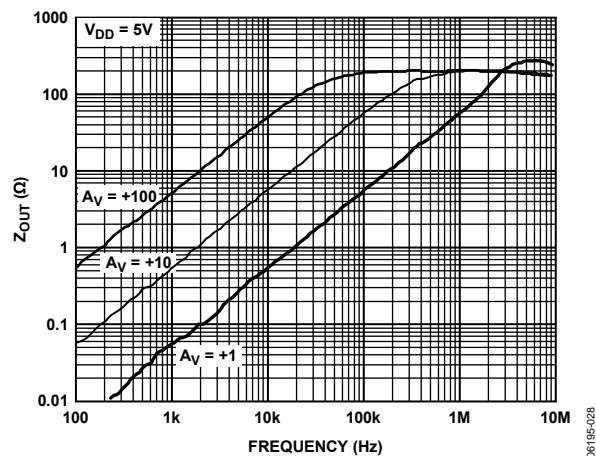


Figure 30. Closed-Loop Output Impedance vs. Frequency

06195-028

# AD8665/AD8666/AD8668

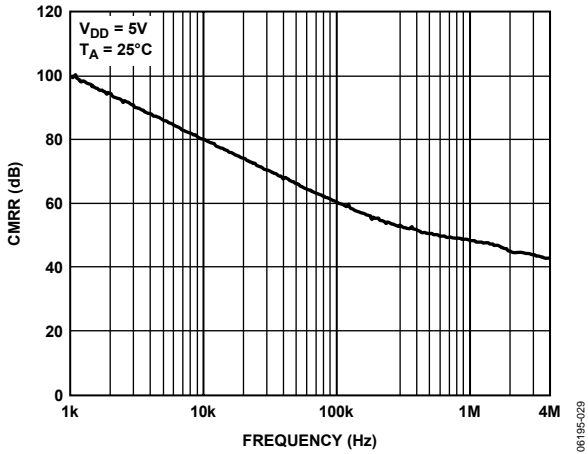


Figure 31. Common-Mode Rejection Ratio vs. Frequency

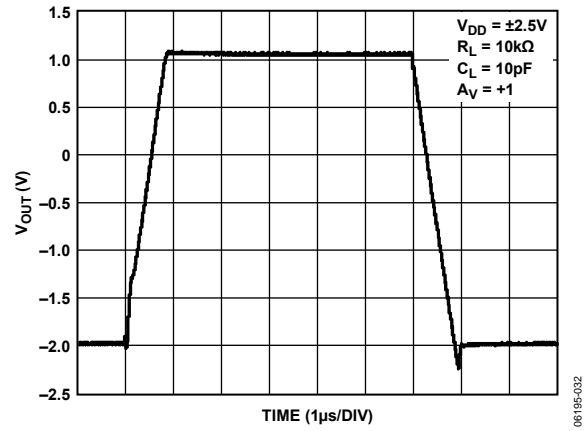


Figure 34. Large-Signal Transient Response

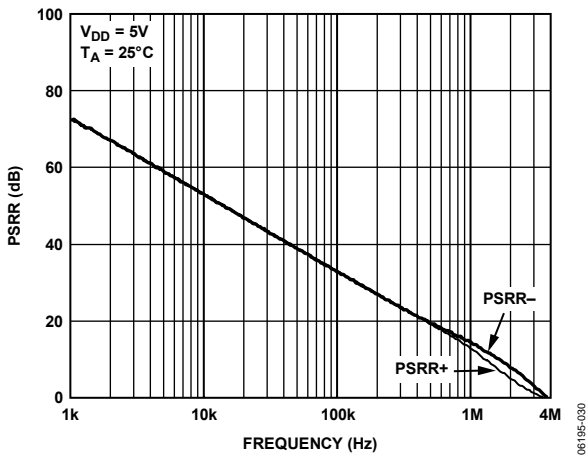


Figure 32. Power Supply Rejection Ratio vs. Frequency

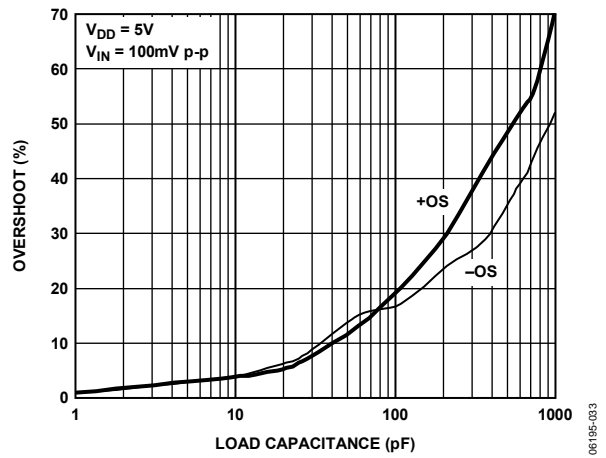


Figure 35. Small-Signal Overshoot vs. Load Capacitance

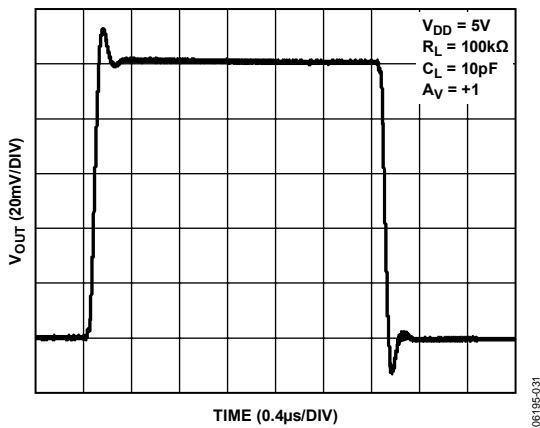


Figure 33. Small-Signal Transient Response

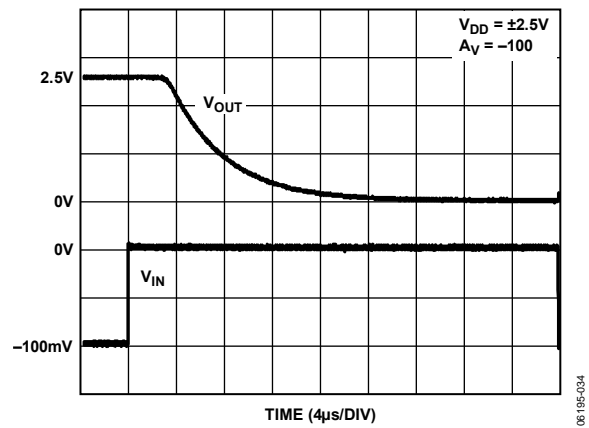


Figure 36. Positive Overload Recovery Time

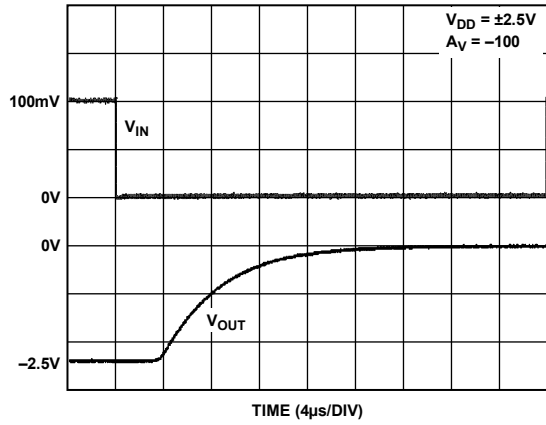


Figure 37. Negative Overload Recovery Time

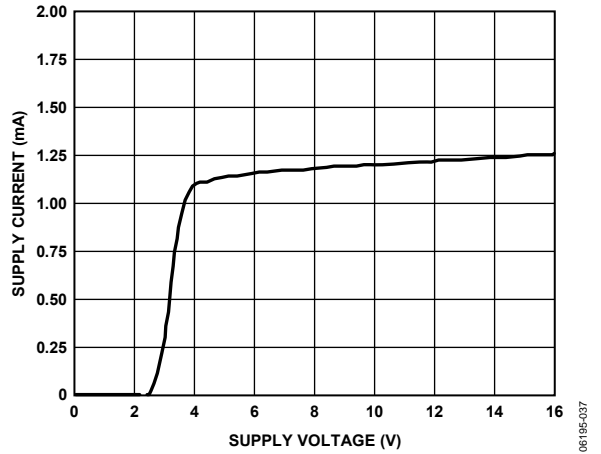


Figure 39. Supply Current vs. Supply Voltage

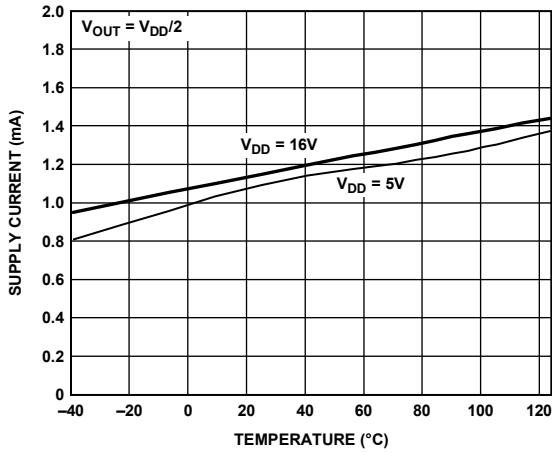


Figure 38. Supply Current vs. Temperature

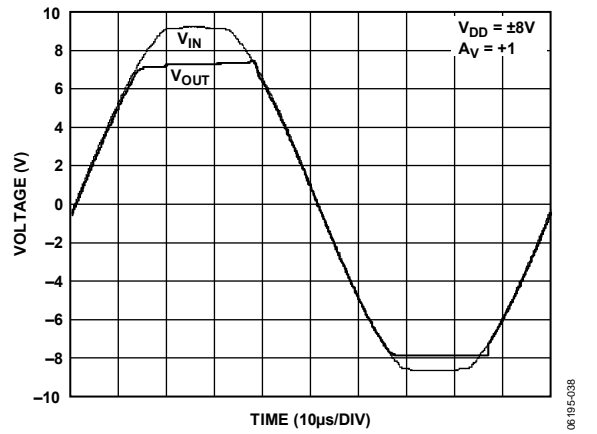
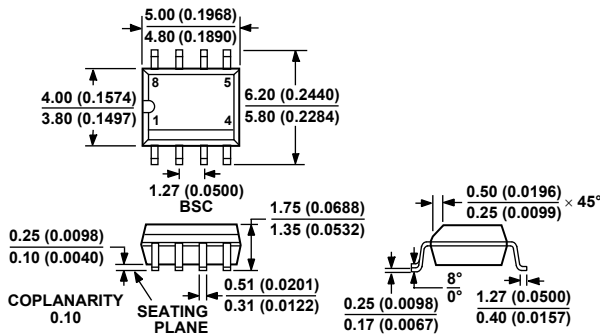


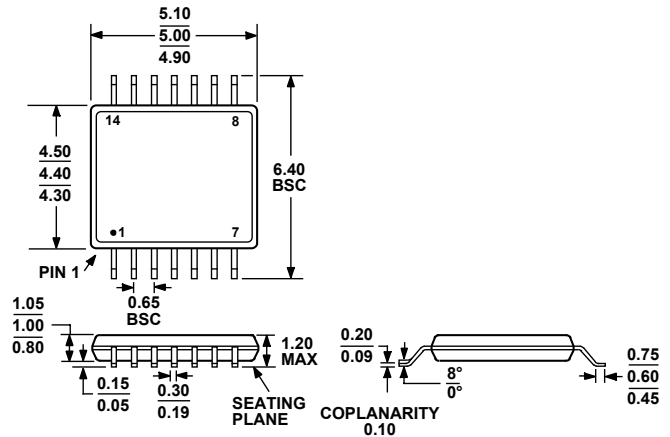
Figure 40. No Output Phase Reversal

OUTLINE DIMENSIONS



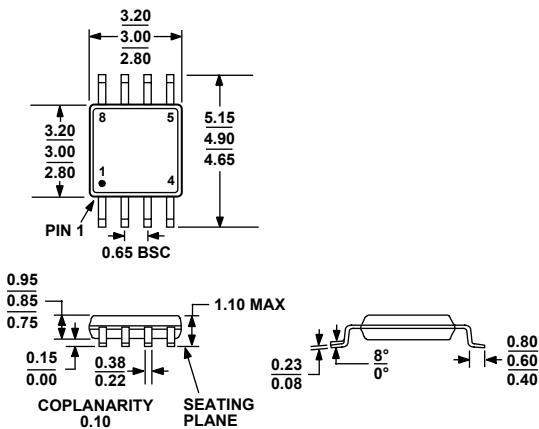
COMPLIANT TO JEDEC STANDARDS MS-012-AA  
 CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 41. 8-Lead Standard Small Outline Package [SOIC\_N]  
 Narrow Body  
 (R-8)  
 Dimensions shown in millimeters and (inches)



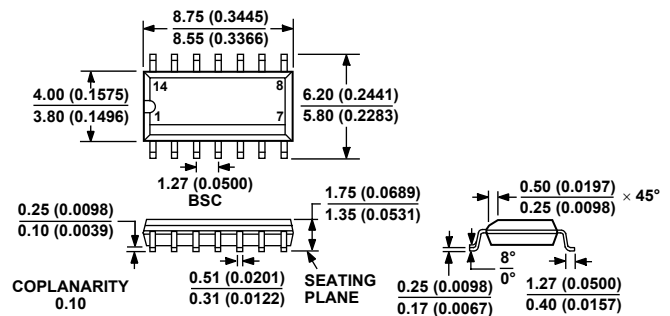
COMPLIANT TO JEDEC STANDARDS MO-153-AB-1

Figure 43. 14-Lead Thin Shrink Small Outline Package [TSSOP]  
 (RU-14)  
 Dimensions shown in millimeters



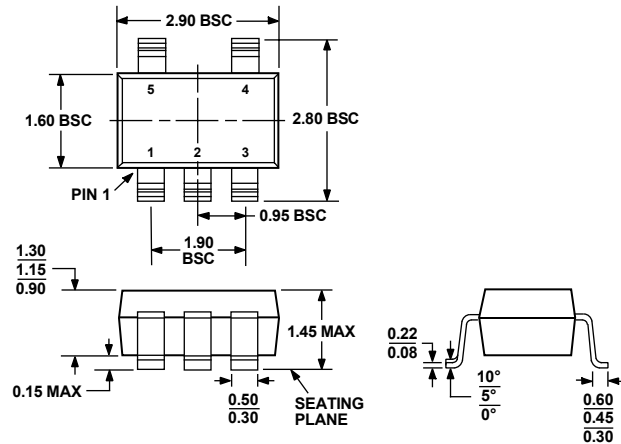
COMPLIANT TO JEDEC STANDARDS MO-187-AA

Figure 42. 8-Lead Mini Small Outline Package [MSOP]  
 (RM-8)  
 Dimensions shown in millimeters



COMPLIANT TO JEDEC STANDARDS MS-012-AB  
 CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 44. 14-Lead Standard Small Outline Package [SOIC\_N]  
 Narrow Body  
 (R-14)  
 Dimensions shown in millimeters and (inches)



COMPLIANT TO JEDEC STANDARDS MO-178-AA

Figure 45. 5-Lead Small Outline Transistor Package [SOT-23] (RJ-5)

Dimensions shown in millimeters

**ORDERING GUIDE**

Model	Temperature Range	Package Description	Package Option	Branding
AD8665ARZ <sup>1</sup>	-40°C to +125°C	8-Lead SOIC_N	R-8	
AD8665ARZ-REEL <sup>1</sup>	-40°C to +125°C	8-Lead SOIC_N	R-8	
AD8665ARZ-REEL7 <sup>1</sup>	-40°C to +125°C	8-Lead SOIC_N	R-8	
AD8665ARJZ-R2 <sup>1</sup>	-40°C to +125°C	5-Lead SOT-23	RJ-5	A1B
AD8665ARJZ-REEL <sup>1</sup>	-40°C to +125°C	5-Lead SOT-23	RJ-5	A1B
AD8665ARJZ-REEL7 <sup>1</sup>	-40°C to +125°C	5-Lead SOT-23	RJ-5	A1B
AD8666ARZ <sup>1</sup>	-40°C to +125°C	8-Lead SOIC_N	R-8	
AD8666ARZ-REEL <sup>1</sup>	-40°C to +125°C	8-Lead SOIC_N	R-8	
AD8666ARZ-REEL7 <sup>1</sup>	-40°C to +125°C	8-Lead SOIC_N	R-8	
AD8666ARMZ-R2 <sup>1</sup>	-40°C to +125°C	8-Lead MSOP	RM-8	A16
AD8666ARMZ-REEL <sup>1</sup>	-40°C to +125°C	8-Lead MSOP	RM-8	A16
AD8668ARZ <sup>1</sup>	-40°C to +125°C	14-Lead SOIC_N	R-14	
AD8668ARZ-REEL <sup>1</sup>	-40°C to +125°C	14-Lead SOIC_N	R-14	
AD8668ARZ-REEL7 <sup>1</sup>	-40°C to +125°C	14-Lead SOIC_N	R-14	
AD8668ARUZ <sup>1</sup>	-40°C to +125°C	14-Lead TSSOP	RU-14	
AD8668ARUZ-REEL <sup>1</sup>	-40°C to +125°C	14-Lead TSSOP	RU-14	

<sup>1</sup> Z = Pb-free part.

**AD8665/AD8666/AD8668**

**NOTES**

**NOTES**

**AD8665/AD8666/AD8668**

## **NOTES**